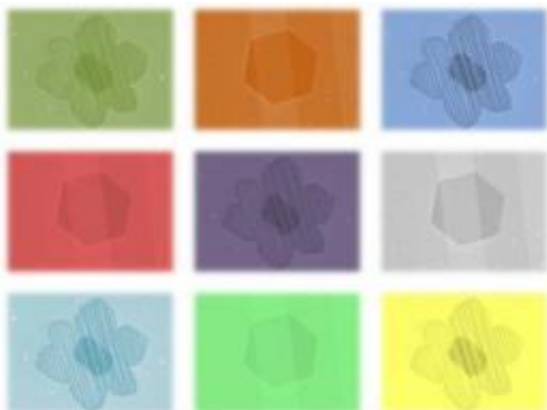


# Hydrogen may be key to growth of high-quality graphene

July 18 2011

---



Graphene grains come in several different shapes. Hydrogen gas controls the grains' appearance. Credit: ORNL

A new approach to growing graphene greatly reduces problems that have plagued researchers in the past and clears a path to the crystalline form of graphite's use in sophisticated electronic devices of tomorrow.

Findings of researchers at the Department of Energy's Oak Ridge National Laboratory demonstrate that hydrogen rather than carbon dictates the graphene grain shape and size, according to a team led by ORNL's Ivan Vlassiuk, a Eugene Wigner Fellow, and Sergei Smirnov, a professor of chemistry at New Mexico State University. This research is published in *ACS Nano*.

"Hydrogen not only initiates the graphene growth, but controls the graphene shape and size," Vlassiouk said. "In our paper, we have described a method to grow well-defined graphene grains that have perfect hexagonal shapes pointing to the faultless single [crystal structure](#)."

In the past two years, graphene growth has involved the [decomposition](#) of carbon-containing gases such as methane on a [copper foil](#) under [high temperatures](#), the so-called [chemical vapor deposition](#) method. Little was known about the exact process, but researchers knew they would have to gain a better understanding of the growth mechanism before they could produce high-quality graphene films.

Until now, grown graphene films have consisted of irregular- shaped graphene grains of different sizes, which were usually not single crystals.

"We have shown that, surprisingly, it is not only the carbon source and the substrate that dictate the growth rate, the shape and size of the graphene grain," Vlassiouk said. "We found that hydrogen, which was thought to play a rather passive role, is crucial for graphene growth as well. It contributes to both the activation of adsorbed molecules that initiate the growth of graphene and to the elimination of weak bonds at the grain edges that control the quality of the graphene."

Using their new recipe, Vlassiouk and colleagues have created a way to reliably synthesize graphene on a large scale. The fact that their technique allows them to control grain size and boundaries may result in improved functionality of the material in transistors, semiconductors and potentially hundreds of [electronic devices](#).

Implications of this research are significant, according to Vlassiouk, who said, "Our findings are crucial for developing a method for growing ultra-large-scale single domain graphene that will constitute a major

breakthrough toward [graphene](#) implementation in real-world devices."

**More information:** [pubs.acs.org/doi/abs/10.1021/mn201978y](https://pubs.acs.org/doi/abs/10.1021/mn201978y)

Provided by Oak Ridge National Laboratory

Citation: Hydrogen may be key to growth of high-quality graphene (2011, July 18) retrieved 8 August 2024 from <https://phys.org/news/2011-07-hydrogen-key-growth-high-quality-graphene.html>

This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.